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2004 02 02

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(43)

10-2002-0094355
2002 12 18

(73) 416

(72) APT407 202

(74)
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(54)

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가

가 ,

(static random access memory) (dynamic random access memory)

(mask read only memory: MROM), (program mable read only memory:PROM), 가 (erasable programmable read only memory:EPROM), 가 (electrically erasable programmable read only memory:EEPROM)

MROM, PROM, EPROM) (on-board) EEPROM 가

가 EEPROM 가 EE PROM EEPROM 가 (Flash) EEPROM NAND AND EEPROM () 가

trate:10) (n) (12) , (12) 5 (p) (subs (14) (16) 100 (16) (14) (18) (18) (18)) 5 가 (18) (hot electron inj (12) ection) (14) (10) , (18) , 9V 가 (14) 가 (16) 5V 가 (10) 가 (18) 4.5V 가 , (14) 1V 가 (18) 가 가 (14) (12) 가 가 6V-7V (10) (18) (Fowler-Nordheim) (F-N) 6 F-N -9V 가 (10) F-N (12) 9V 가 (high-impedan ce) (18) (10)

F-N (12) F-N (16) 6-7 MV/cm 가 가 100

F-N 가 (6) 가

64K byte (sector)

6 가 (14) (12) 가 - (on-cell)

1V-3V " - "

0V (uniformity) 가 0V 1V-3V (over)

(12) (10) (18) 2V-5V 가

(14) (+) 6V-9V 가 (16) 1V-3V

1 1 (Hierarchical) (Row Decoder)

(W/L) (coding) 101,201,301,401 (W/L) (B/L)

가 102,202,302,402 (pass Gate) 100 (B/L) (101)

Y- (102) W/L (101) W/L B/L (21,31) 가 (101)

(100) 가 (200,300,400) / / 가

1 (100) (200) (21,22,31,32) (100) (200) W/L

(100,200) W/L (GWL) GWL0~GWLn

W/L (21,22,31,32) (100) (X)

MATX0가 X- 가 가 Y (MAT

2,4) Y0가 (100) GWL0~GWLn (21,31) 가 가 W/L

(102) I(6) (Y-address) MATX0 Y-

(B/L) (12) (102) (14) 가 (D/L)

MATX0 가 (12) (101,201) (14) (D/L)

MATXi (300,400) / (B/L) 1(Metal1)

1 W/L (D/L) GWL

1 2(Metal2) (Hierarchical)

가 MATXi 가 가

MATX가 가 가 가

(aspect)

가 ,
가

가 ,

가

2 (100,200,300,400)
 (21-24,31-34) ,
 (101,201,301,401) ,
 (103,203,303,403) (21,22)
 Y- (2) (4) (GW
 (31,32) (23,24) (33,34) (2)
 L0,GWLn) (4) (GWL0i,GWLni) Y-
 (103,203,303,403) (101,201,301,401)
 (LCD;7) Y- (103,203) Y- (303,4
 03) (GCD;700,800) (500,600) (500,600)
) (12) (14)
 W/L B/L
 가
 (B/L) m (W/L) n (500,600) m Y-
 (103,203,303,403) (D/L) (12) (14)가 (D/L)
 1 2 (100,200) (300,400) W/L
 (100,300) (200,400) B/L
 (12) (14)
 1 가 가
 가 가 (300) (301)
 W/L0-WLi (301) 1(Metal1) W/L W/L 2 B/L0-B/L
 n 1 B/L B/L 3 3(Metal3)
 2(Metal2) (301) 2 3 W/L B/L
 2 3 B/L W/L

4 2 가 W/L GWL 4 , (2,4) 32
 (21-24,31-34) (2,4)
 (7) , ()
 700,800)가 2 가 가
 (100) (MC1) 64K byte W/L
 (X-address) MATX0
 (2,4) GWL0~GWLn 가 , MATY0가 (100)
 (21,31) 가 (21)가 ,
 W/L , 2 1
 (100) (B/L) MATY0 가
 (700) 가 (700) (500)
 () T1 (12)
 (14) (D/L) (GBL0)
 MATX0 (100) (7)
 Y- (103) (N1)가
 (101) (B/L) (GBL0)
 (MC1)
 (12) (12)
 (14) 가 (D/L)
 (GBL0) (B/L) (MC1)
 (Hierachical) B/L
 1 1 ,
 가 가 , ,
 , 3 가

(57)

1.

Y-

2.

1

가

.

- () 3.
- () 4.
- () 5.
- () 6.
- () 7.

;

Y-

:

,

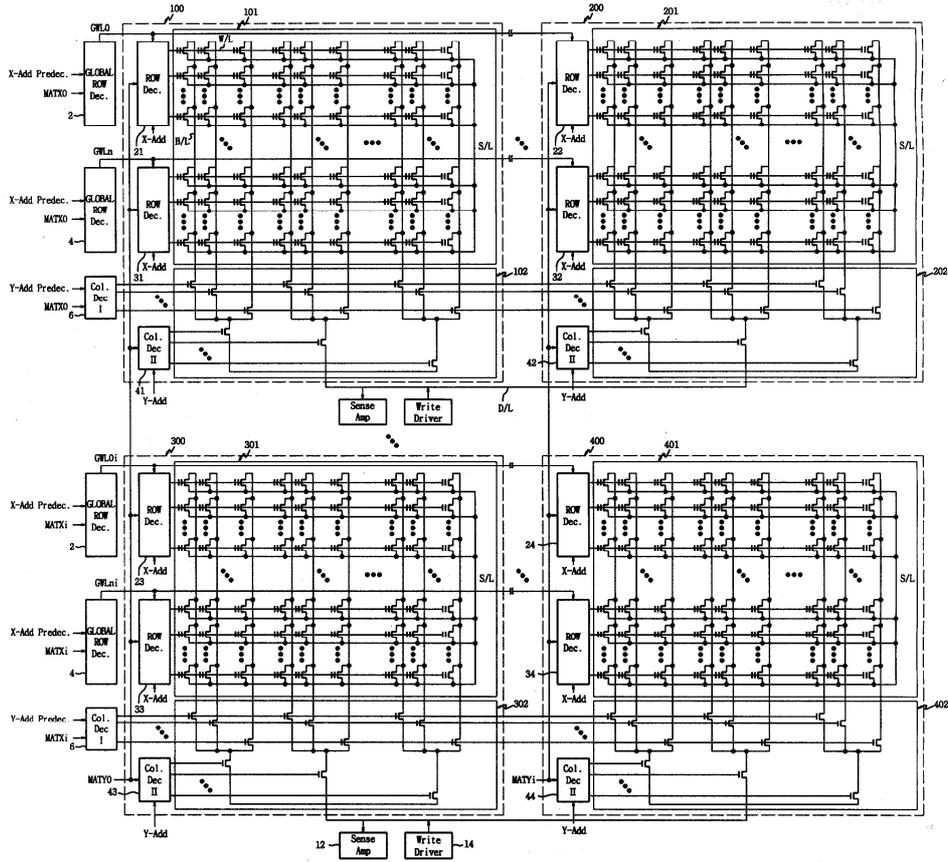
Y-

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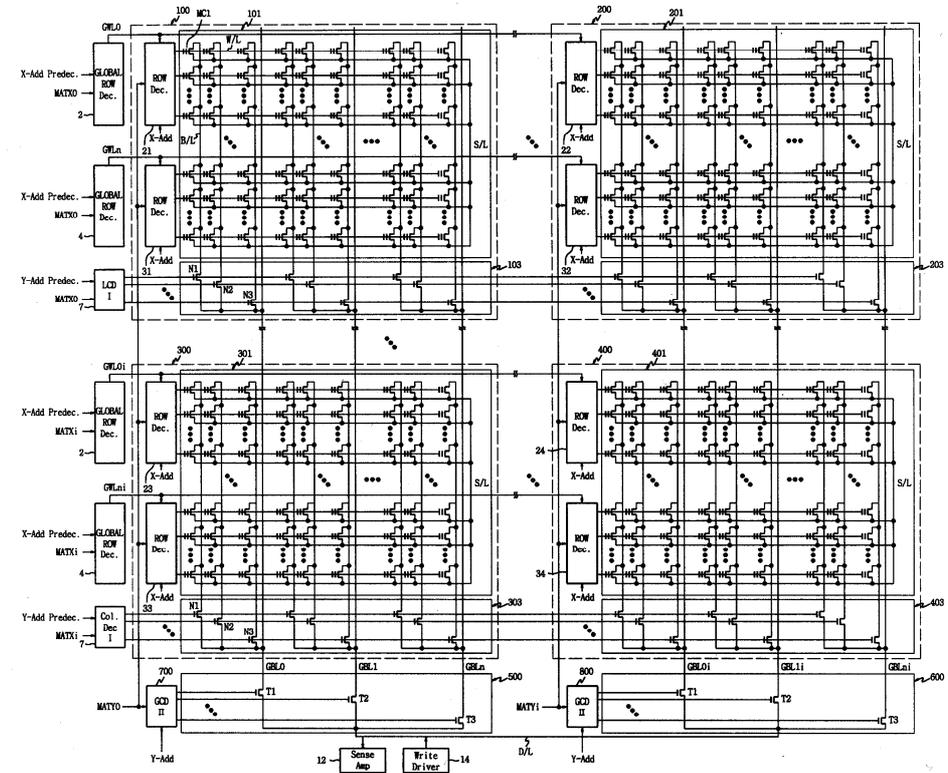
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- () 8.
- () 9.
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- () 12.
- () 13.

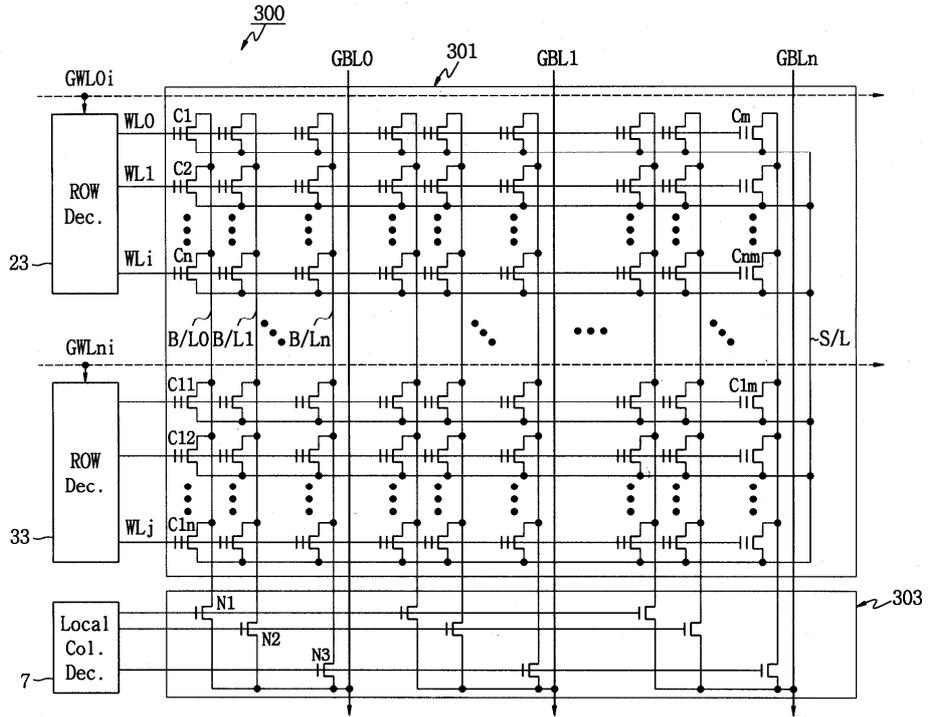
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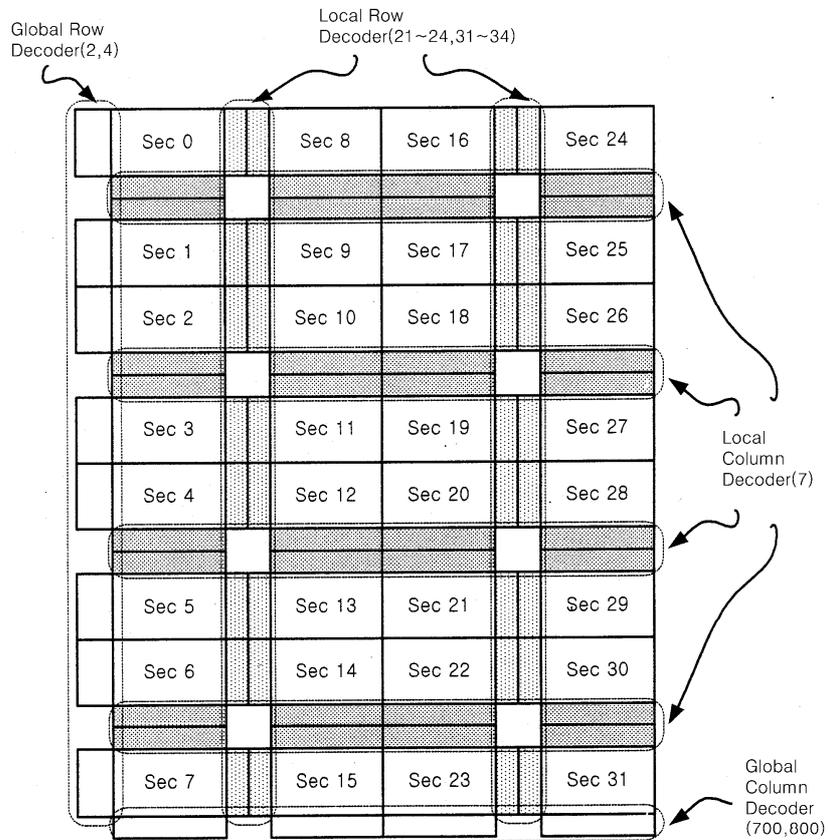
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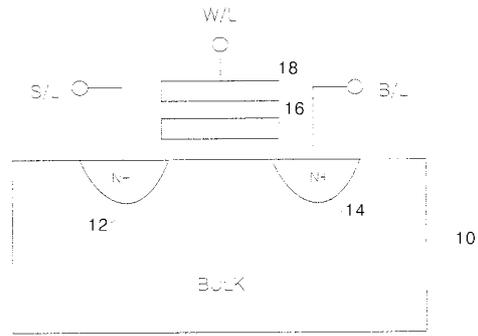
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Operation	W/L	B/L	S/L	BULK
Program	9V	5V	0V	0V
Erase	-9V	Floating	Floating	9V
Read	4.5V	1V	0V	0V